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C27 series

Series/Type: Ordering code: Absolute pressure sensor die Date: 2009-08-03 Version:

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C27 series

Absolute pressure sensor die

Applications

- Medical devices
- Automotive
- Automation

Features

- Piezoresistive MEMS technology
- Dimensions: 3.05 × 3.05 mm
- Square diaphragm
- Measured media (front side): Dry non-aggressive gases. Unsuitable for substances which react with glass, silicon or aluminum.
- Whetstone bridge with mV output, ratiometric to supply voltage
- Rated pressure ranges 0.25 up to 1.0 bar

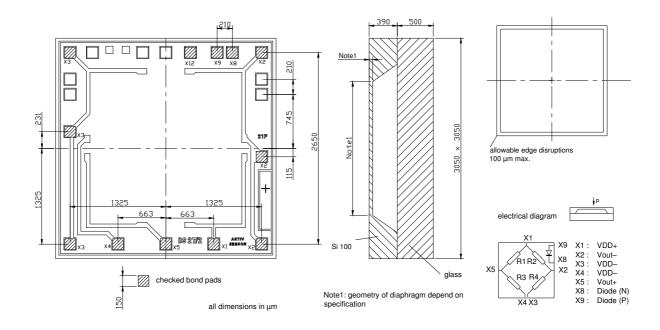
Options

Temperature sensing diode

Delivery mode

Tray

Dimensional drawings



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Technical data

Absolute maximum ratings

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Supply voltage		·	·		•	
Maximum supply voltage	V _{DD}	Without damage 1)			10	V
Temperature ranges						
Operating temperature range	T _a	2)	-40		135	°C
		For t <15 min	-40		140	°C
Storage temperature range	T _{st}	3)	-40		150	°C
Pressure ranges		·	·		·	
Operating pressure ranges	pr	Absolute pressure 4)	0 0.25		0 1.0	bar
Over pressure	p _{ov}	Absolute pressure ⁵⁾	3			pr
Burst pressure	p _{berst}	Absolute pressure 6)	5			pr

Electrical specifications

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Supply voltage / bridge resistant	-			- 71-		
Operating supply voltage	V _{DD}	7)	1.0		5.0	V
Total bridge resistance	Rs	@ 25 °C ⁸⁾	2.6	3.3	4.0	kΩ
Temperature coefficient of total bridge resistance	α _{Rs}	@ 25 ℃ ⁹⁾	2.1	2.4	2.7	10 ⁻³ /K
	β_{Rs}		4	6	8	10 ⁻⁶ /K ²
Output signal @ V _{DD} = 5 V	-		•	•	•	•
Offset	V ₀	@ 25 °C ¹⁰⁾	-30	0	30	mV
Sensitivity	S	@ 25 °C ¹³⁾	See next table			mV/bar
Temperature coefficient of the sensitivity	α _S	— @ 25 ℃ ¹⁵⁾	-2.5	-2.2	-1.9	10 ⁻³ /K
	βs		3	5	8	10 ⁻⁶ /K ²
Pressure hysteresis	pHys	16)	-0.1		0.1	% FS
Optional temperature sensing di	ode					·
Forward diode voltage	V _F	@ 25 °C, $I_F = 50 \ \mu A^{17}$	550	600	650	mV
Temperature coefficient of forward diode voltage	TCVF	@ 25 °C, $I_F = 50 \ \mu A^{18)}$	-2.4	-2.2	-2.0	mV/K
Long-term stability (Full scale no	ormal output	t FSON = 120 mV)				
Temperature hysteresis of offset	THV₀	19)	-0.35	±0.2	0.35	% FSON
Temperature cycle drift of offset	TCDV ₀	19)	-0.25	±0.1	0.25	% FSON
High temperature drift of offset	HTDV₀	19)	-0.25	±0.1	0.25	% FSON
Long term stability of offset	LTSV ₀	19)	-0.45	±0.3	0.45	% FSON

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Operating pressures and ordering codes

Parameter @ 25 °C, V _{DD} = 5 V	Symbol	Тур.	Тур.	Тур.	Units
Operating pressure 4)	pr	0.250	0.400	1.000	bar
Temperature coefficient of offset voltage (unglued) ¹¹⁾ [min/typ/max]	TCV ₀ ⁻	-8/±4/8	-8/±4/8	-8/±4/8	μV/VK
	TCV ₀ ⁺	-4/±2/4	-4/±2/4	-4/±2/4	μV/VK
Nonlinearity ¹⁴⁾ [typ/max]	L	±0.2/±0.3	±0.2/±0.3	±0.3/±0.4	% FS
Sensitivity ¹³⁾ [min/typ/max]	S	300/400/480	225/300/375	90/120/150	mV/bar
Temperature sensing diode present		yes	yes	yes	
Product type		AEA 0.250 C27/2 G05 D	AEA 0.400 C27/2 G05 D	AEA 1.000 C27/2 G05 D	
Ordering code		B58600C5010A003	B58600C5010A004	B58600C5010A005	

Other operating pressures upon request.

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Absolute pressure sensor die

Symbols and terms

¹⁾ Maximum power supply V_{DD}

This is the maximal allowed voltage, which may be applied to the piezoresistive bridge circuit without damage.

²⁾ Operating temperature range T_a

This is the operating Temperature range $T_{a,min}$ to $T_{a,max}$. Because most of the sensor parameters depend on assembling conditions like gluing, wire bonding etc, the die has to be tested over the operating temperature range by the customer fully assembled. For design verification and process control samples mounted on a TO39 base are tested over a reduced measuring temperature range of $T_{meas,min}$ to $T_{meas,max}$.

³⁾ Storage temperature range T_{st}

If the pressure sensor dies are stored in the temperature range $T_{st,min}$ to $T_{st,max}$ without applied voltage power supply, this will not affect the performance of the pressure sensor dies.

⁴⁾ Operating pressure range p_r

In the operating pressure range 0 to $p_{r,max}$ the pressure sensor die output characteristic is as defined in this specification. **Over pressure p**_{ov}

Pressure cycles in the pressure range 0 to pov do not affect the performance of the pressure sensor dies.

⁶⁾ Burst pressure p_{berst}

5)

Up to the burst pressure p_{berst} the diaphragm of the sensor die will not be destroyed mechanically. This parameter is tested at room temperature on samples mounted on a TO39 base by increasing the applied pressure until the diaphragm is destroyed.

⁷⁾ Operating power supply V_{DD}

The pressure sensor parameters are defined for a power supply voltage of $V_{DD} = 5$ V. In the operating power supply voltage range $V_{DD,min}$ to $V_{DD,max}$ the ratiometric parameters $r(V_{DD})$ like sensitivity, offset voltage and the temperature coefficient of the offset voltage are defined by:

$$r(V_{DD}) = r(5[V]) \frac{V_{DD}}{5[V]}$$

⁸⁾ Total bridge resistance R_s

The total bridge resistance is defined between pad X1 and X3, X4 (see the dimensional drawing in this data sheet) of the closed piezoresistive bridge circuit. The total bridge resistance is in a good approximation the output impedance of the piezoresistive bridge circuit. This parameter is tested completely on a wafer (wafer level test measurement).

⁹⁾ Temperature coefficients of resistance α_{Rs} and β_{Rs} :

The temperature coefficients of resistance are tested for design verification on samples, mounted on a TO39 base over a reduced temperature range $T_{meas,min} = -20$ °C to $T_{meas,max} = 80$ °C with $T_R = 25$ °C. The temperature coefficients of first and second order are defined with the polynomial:

$$\mathbf{P}_{S}(T) = \mathbf{P}_{S}(T = 25^{\circ}C) \left[1 + \alpha_{Rs} \left(T - 25^{\circ}C \right) + \beta_{Rs} \left(T - 25^{\circ}C \right)^{2} \right]$$

The coefficients α_{Rs} and β_{Rs} are calculated using the three measurement points of $R_s(T)$ at $T_{meas,min}$, T_R and $T_{meas,max}$.

¹⁰⁾ Offset voltage V₀

The offset voltage V₀ is the output voltage V_{out}(p = 0 bar abs) at zero absolute pressure and for a bridge voltage power supply V_{DD} = 5 V. Before anodic glass bonding the offset voltage is tested completely on a wafer (wafer level test measurement) with limits -25 mV < V₀ < 25 mV.

For design verification V_0 is measured on samples mounted on a TO39 base by extrapolating the output characteristic to zero bar. It should be noted that this parameter may be influenced by assembly.

$^{11)}\,$ Temperature coefficient of offset voltage TCV_0

The temperature coefficients of offset voltage are defined for a bridge voltage power supply $V_{DD} = 5 \text{ V}$.

These parameters strongly depend on assembly conditions like gluing, wire bonding etc.

The temperature coefficients of offset voltage are tested for design verification on samples, mounted on a TO39 base over a reduced temperature range $T_{meas,min} = -20$ °C to $T_{meas,max} = 80$ °C with $T_{R} = 25$ °C.

Assuming the offset voltage is mainly due to induce stress TCV₀ may be calculated by extrapolating using:

$$V_{0}(T) = \left(1 + \alpha_{s}(T - 25^{\circ}C) + \beta_{s}(T - 25^{\circ}C)^{2}\right) \left(V_{0}(25^{\circ}C) + v_{1}(T - 25^{\circ}C) + v_{2}(T - 25^{\circ}C)^{2}\right)$$



Absolute pressure sensor die

Pressure sensors

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 α_s and β_s are the linear and nonlinear temperature coefficient of the sensitivity respectively (see 15). Therefore TCVo⁺ and TCVo⁻ are defined for the measurement temperature range by:

$$TCVo^{+} = \frac{V_{o}(T_{max}) - V_{o}(25^{\circ}C)}{T_{max} - 25^{\circ}C} \qquad TCVo^{-} = \frac{V_{o}(T_{min}) - V_{o}(25^{\circ}C)}{T_{min} - 25^{\circ}C}$$

12) Full scale value FS

$$FS = V_{out}(p_{rmax}) - V_o$$

¹³⁾ Sensitivity S

The sensitivity is defined for a bridge voltage power supply $V_{DD} = 5$ V. It can be determined by the formula:

$$S = \frac{V_{out}(p_{rmax}) - V_o}{p_{rmax}}$$

This parameter is tested for process control on samples, mounted on a TO39 base.

14) Nonlinearity L

This parameter may be influenced by assembly.

The nonlinearity is measured using the endpoint method. Assuming a characteristic, this can be approximated by a polynomial of second order, where the maximum is at $p_x = p_{rmax}/2$. The nonlinearity is defined at $p_x = p_{rmax}/2$, using the equation:

$$L = \frac{V_{out}(p_x) - V_o}{V_{out}(p_{rmax}) - V_o} - \frac{p_x}{p_{rmax}}$$

This parameter is tested for process control on samples, mounted on a TO39 base.

15) Temperature coefficient of sensitivity α_s and β_s :

These parameters may be influenced by assembly. The temperature coefficients of sensitivity are tested for design verification on samples, mounted on a TO39 base over a reduced temperature range $T_{meas,min} = -20$ °C to $T_{meas,max} = 80$ °C with $T_{R} = 25$ °C. The temperature coefficients of first and second order are defined with the polynomial:

$$S(T) = S(T = 25^{\circ}C) \left[1 + \alpha_{S}(T - 25^{\circ}C) + \beta_{S}(T - 25^{\circ}C)^{2} \right]$$

The coefficients α_S and β_S are calculated using the three measurement points of S(T) at T_{meas.min}, T_R and T_{meas.max}.

16) Pressure hysteresis pHys

The pressure hysteresis is the difference between output voltages at constant pressure and constant temperature while applying a pressure cycle with pressure steps of pr, min, p1, p2, p3, pr, max, p3, p2, p1, pr, min:

$$pHys = \frac{V_{out,2}(p_k) - V_{out,1}(p_k)}{FS}$$

With k = min, 1, 2, 3, max. The pressure steps are: prmin = 0, p₁ = 0.25 · p_{r,max}, p₂ = 0.5 · p_{r,max}, p₃ = 0.75 · p_{r,max}, p_{r,max}. This parameter is tested for design verification on samples, mounted on a TO39 base.

$^{17)}\,$ Forward diode voltage V_F

The voltage drop is measured across anode and cathode by a forward current of 47 µA.

This parameter is tested completely on a wafer (wafer level test measurement).

¹⁸⁾ Temperature coefficient of forward diode voltage TCV_F

The temperature sensitivity of diode voltage drop is defined by the measured values at −20 °C and 80 °C using the equation:

$$TCV_{F} = \frac{V_{F}(T_{meas,max}) - V_{F}(T_{meas,min})}{T_{meas,max} - T_{meas,min}}$$

With T_{meas,min} = −20 °C and T_{meas,max} = 80 °C and the measurement is done with a constant current of 50 µA. The estimated temperature coefficient is also valid at temperatures between −40 °C and 135 °C. This parameter is tested for design verification on samples mounted on a TO39 base.

19) **Reliability data**

For long-term stability of offset voltage LTSV₀ please refer to the defined Aktiv Sensor's standard AS100001 in chapter "Reliability data" on the internet.

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Absolute pressure sensor die

Cautions and warnings

Storage (general)

All pressure sensors should be stored in their original packaging. They should not be placed in harmful environments such as corrosive gases nor exposed to heat or direct sunlight, which may cause deformations. Similar effects may result from extreme storage temperatures and climatic conditions. Avoid storing the sensor dies in an environment where condensation may form or in a location exposed to corrosive gases, which will adversely affect their performance. Plastic materials should not be used for wrapping/packing when storing or transporting these dies, as they may become charged. Pressure sensor dies should be used soon after opening their seal and packaging.

Operation (general)

Media compatibility with the pressure sensors must be ensured to prevent their failure. The use of other media can cause damage and malfunction. Never use pressure sensors in atmospheres containing explosive liquids or gases.

Ensure pressure equalization to the environment, if gauge pressure sensors are used. Avoid operating the pressure sensors in an environment where condensation may form or in a location exposed to corrosive gases. These environments adversely affect their performance.

If the operating pressure is not within the rated pressure range, it may change the output characteristics. This may also happen with pressure sensor dies if an incorrect mounting method is used. Be sure that the applicable pressure does not exceed the overpressure, as it may damage the pressure sensor.

Do not exceed the maximum rated supply voltage nor the rated storage temperature range, as it may damage the pressure sensor.

Temperature variations in both the ambient conditions and the media (liquid or gas) can affect the accuracy of the output signal from the pressure sensors. Be sure to check the operating temperature range and thermal error specification of the pressure sensors to determine their suitability for the application.

Connections must be wired in accordance with the terminal assignment specified in the data sheets. Care should be taken as reversed pin connections can damage the pressure transmitters or degrade their performance. Contact between the pressure sensor terminals and metals or other materials may cause errors in the output characteristics.

Design notes (dies)

This specification describes the mechanical, electrical and physical requirements of a piezoresistive sensor die for measuring pressure. The specified parameters are valid for the pressure sensor die with pressure application either to the front or back side of the diaphragm as described in the data sheet. Pressure application to the other side may result in differing data. Most of the parameters are influenced by assembly conditions. Hence these parameters and the reliability have to be specified for each specific application and tested over its temperature range by the customer.

Handling/Mounting (dies)

Pressure sensor dies should be handled appropriately and not be touched with bare hands. They should only be picked up manually by the sides using tweezers. Their top surface should never be touched with tweezers. Latex gloves should not be used for handling them, as this will inhibit the curing of the adhesive used to bond the die to the carrier. When handling, be careful to avoid cuts caused by the sharp-edged terminals. The sensor die must not be contaminated during manufacturing processes (gluing, soldering, silk-screen process).

The package of pressure sensor dies should not to be opened until the die is mounted and should be closed after use. The sensor die must not be cleaned. The sensor die must not be damaged during the assembly process (especially scratches on the diaphragm).

Soldering (transducers, transmitters)

The thermal capacity of pressure sensors is normally low, so steps should be taken to minimize the effects of external heat. High temperatures may lead to damage or changes in characteristics.

A non-corrosive type of flux resin should normally be used and complete removal of the flux is recommended. Avoid rapid cooling due to dipping in solvent. Note that the output signal may change if pressure is applied to the terminals during soldering.

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